PDTA143Z series

PNP resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

Rev. 7 — 5 December 2011

Product data sheet

1. Product profile

1.1 General description

PNP Resistor-Equipped Transistor (RET) family in Surface-Mounted Device (SMD) plastic packages.

Table 1. Product overview

Type number	Package			NPN	Package
	NXP	JEITA	JEDEC	complement	configuration
PDTA143ZE	SOT416	SC-75	-	PDTC143ZE	ultra small
PDTA143ZM	SOT883	SC-101	-	PDTC143ZM	leadless ultra small
PDTA143ZT	SOT23	-	TO-236AB	PDTC143ZT	small
PDTA143ZU	SOT323	SC-70	-	PDTC143ZU	very small

1.2 Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

1.3 Applications

- Digital applications in automotive and industrial segments
- Control of IC inputs

- Cost-saving alternative for BC847/857 series in digital applications
- Switching loads

1.4 Quick reference data

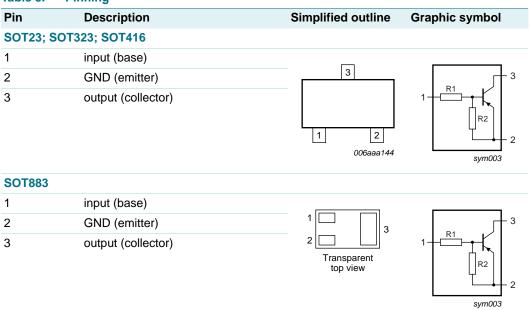
Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	-50	V
Io	output current		-	-	-100	mA
R1	bias resistor 1 (input)		3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio		8	10	12	



2. Pinning information

Table 3. Pinning



3. Ordering information

Table 4. Ordering information

PDTA143ZE SC-75 plastic surface-mounted package; 3 leads SOT4 PDTA143ZM SC-101 leadless ultra small plastic package; 3 solder lands; body 1.0 × 0.6 × 0.5 mm PDTA143ZT - plastic surface-mounted package; 3 leads SOT2	Type number	Package	Package					
PDTA143ZM SC-101 leadless ultra small plastic package; 3 solder lands; SOT8 body $1.0 \times 0.6 \times 0.5$ mm PDTA143ZT - plastic surface-mounted package; 3 leads SOT2		Name	Description	Version				
	PDTA143ZE	SC-75	plastic surface-mounted package; 3 leads	SOT416				
	PDTA143ZM	SC-101		SOT883				
PDTA143ZU SC-70 plastic surface-mounted package; 3 leads SOT3	PDTA143ZT	-	plastic surface-mounted package; 3 leads	SOT23				
	PDTA143ZU	SC-70	plastic surface-mounted package; 3 leads	SOT323				

4. Marking

Table 5. Marking codes

Type number	Marking code ^[1]
PDTA143ZE	37
PDTA143ZM	DP
PDTA143ZT	*19
PDTA143ZU	*47

^{[1] * =} placeholder for manufacturing site code

5. Limiting values

Table 6. Limiting values

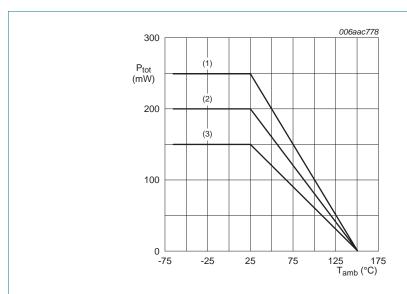
In accordance with the Absolute Maximum Rating System (IEC 60134).

			<u> </u>		
Symbol	Parameter	Conditions	Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter	-	-50	V
V_{CEO}	collector-emitter voltage	open base	-	-50	V
V_{EBO}	emitter-base voltage	open collector	-	-5	V
VI	input voltage				
	positive		-	+5	V
	negative		-	-30	V
Io	output current		-	-100	mA
I _{CM}	peak collector current	single pulse; $t_p \le 1 \text{ ms}$	-	-100	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$			
	PDTA143ZE (SOT416)		[1][2] -	150	mW
	PDTA143ZM (SOT883)		[2][3]	250	mW
	PDTA143ZT (SOT23)		<u>[1]</u> -	250	mW
	PDTA143ZU (SOT323)		<u>[1]</u> -	200	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

^[2] Reflow soldering is the only recommended soldering method.

^[3] Device mounted on an FR4 PCB with 70 μm copper strip line, standard footprint.



- (1) SOT23; FR4 PCB, standard footprint SOT883; FR4 PCB with 70 μm copper strip line, standard footprint
- (2) SOT323; FR4 PCB, standard footprint
- (3) SOT416; FR4 PCB, standard footprint

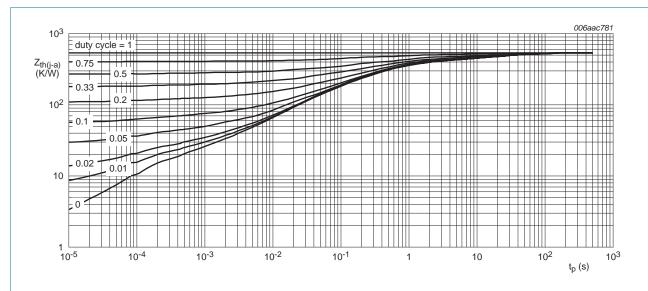
Fig 1. Power derating curves

6. Thermal characteristics

Table 7. Thermal characteristics

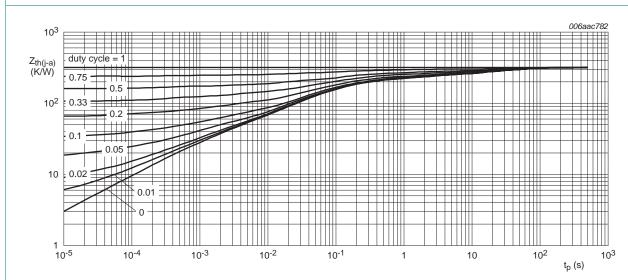
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air				
	PDTA143ZE (SOT416)		[1][2]	-	830	K/W
	PDTA143ZM (SOT883)		[2][3]	-	500	K/W
	PDTA143ZT (SOT23)		[1] -	-	500	K/W
	PDTA143ZU (SOT323)		<u>[1]</u> _	-	625	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Reflow soldering is the only recommended soldering method.
- [3] Device mounted on an FR4 PCB with 70 μm copper strip line, standard footprint.



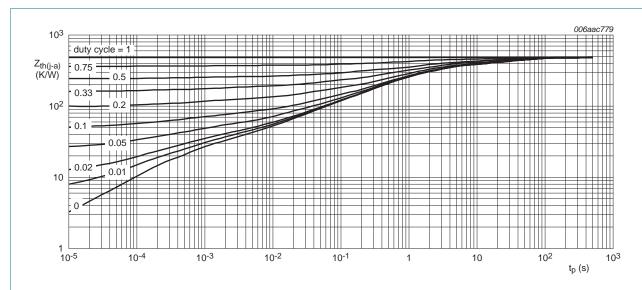
FR4 PCB, standard footprint

Fig 2. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTA143ZE (SOT416); typical values



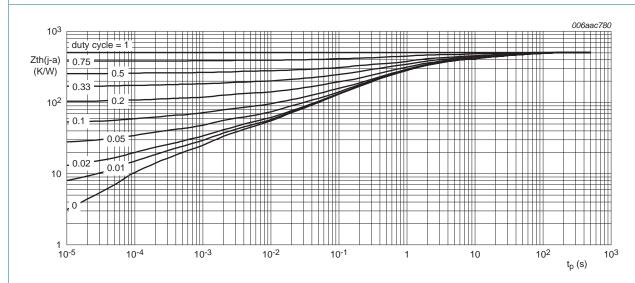
FR4 PCB, 70 µm copper strip line

Fig 3. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTA143ZM (SOT883); typical values



FR4 PCB, standard footprint

Fig 4. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTA143ZT (SOT23); typical values



FR4 PCB, standard footprint

Fig 5. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTA143ZU (SOT323); typical values

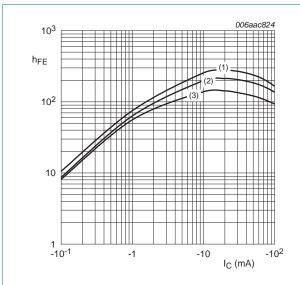
7. Characteristics

Table 8. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off current	$V_{CB} = -50 \text{ V}; I_E = 0 \text{ A}$	-	-	-100	nA
I _{CEO}	CEO collector-emitter cut-off current	$V_{CE} = -30 \text{ V}; I_B = 0 \text{ A}$	-	-	-1	μΑ
		$V_{CE} = -30 \text{ V}; I_{B} = 0 \text{ A};$ $T_{j} = 150 ^{\circ}\text{C}$	-	-	-5	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_C = 0 \text{ A}$	-	-	-170	μΑ
h _{FE}	DC current gain	$V_{CE} = -5 \text{ V}; I_{C} = -10 \text{ mA}$	100	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = -5 \text{ mA}; I_B = -0.25 \text{ mA}$	-	-	-100	mV
$V_{I(off)}$	off-state input voltage	$V_{CE} = -5 \text{ V}; I_{C} = -100 \mu\text{A}$	-	-0.6	-0.5	V
$V_{I(on)}$	on-state input voltage	$V_{CE} = -0.3 \text{ V}; I_{C} = -5 \text{ mA}$	-1.3	-0.9	-	V
R1	bias resistor 1 (input)		3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio		8	10	12	
C _c	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz	-	-	3	pF
f _T	transition frequency	$V_{CE} = -5 \text{ V}; I_{C} = -10 \text{ mA};$ [1] $f = 100 \text{ MHz}$	-	180	-	MHz

^[1] Characteristics of built-in transistor



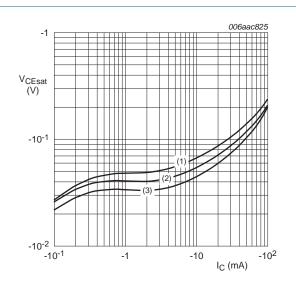
$$V_{CE} = -5 \text{ V}$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3) $T_{amb} = -40 \, ^{\circ}C$

Fig 6. DC current gain as a function of collector current; typical values



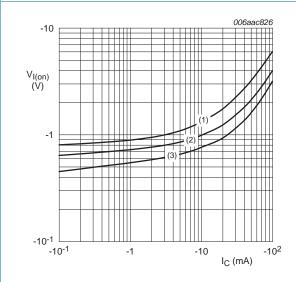
$$I_{\rm C}/I_{\rm B} = 20$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig 7. Collector-emitter saturation voltage as a function of collector current; typical values



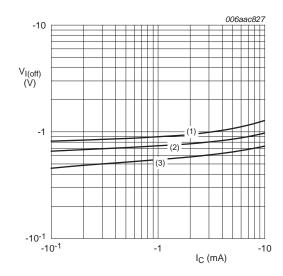


(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3) T_{amb} = 100 °C

Fig 8. On-state input voltage as a function of collector current; typical values



$$V_{CE} = -5 \text{ V}$$

(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3) $T_{amb} = 100 \, ^{\circ}C$

Fig 9. Off-state input voltage as a function of collector current; typical values

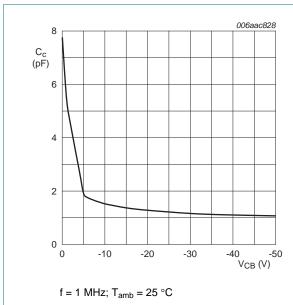


Fig 10. Collector capacitance as a function of collector-base voltage; typical values

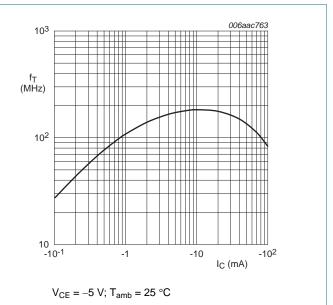


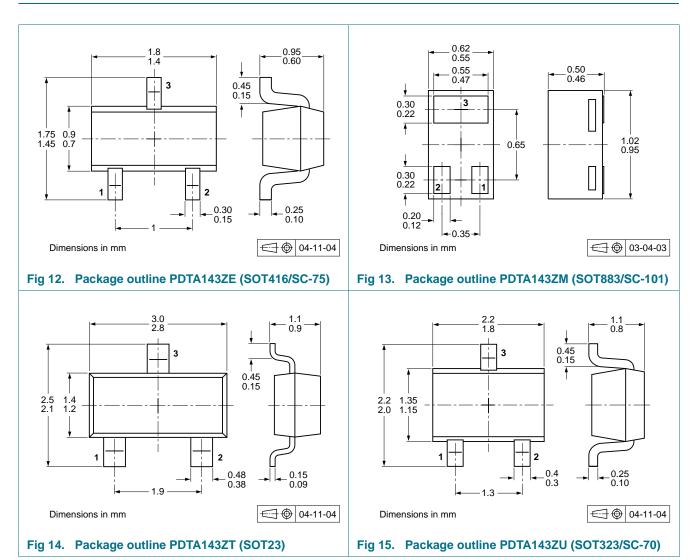
Fig 11. Transition frequency as a function of collector current; typical values of built-in transistor

8. Test information

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

9. Package outline



10. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing	Packing quantity			
			3000	5000	10000		
PDTA143ZE	SOT416	4 mm pitch, 8 mm tape and reel	-115	-	-135		
PDTA143ZM	SOT883	2 mm pitch, 8 mm tape and reel	-	-	-315		
PDTA143ZT	SOT23	4 mm pitch, 8 mm tape and reel	-215	-	-235		
PDTA143ZU	SOT323	4 mm pitch, 8 mm tape and reel	-115	-	-135		

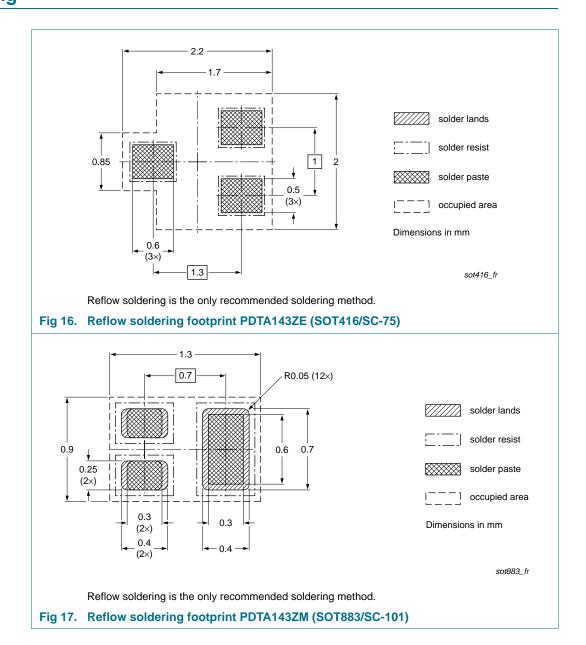
[1] For further information and the availability of packing methods, see Section 14.

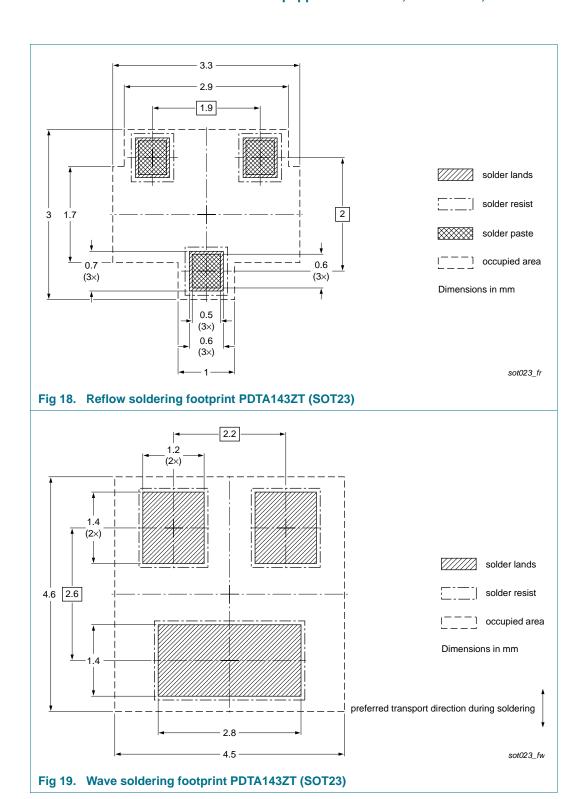
PDTA143Z_SER

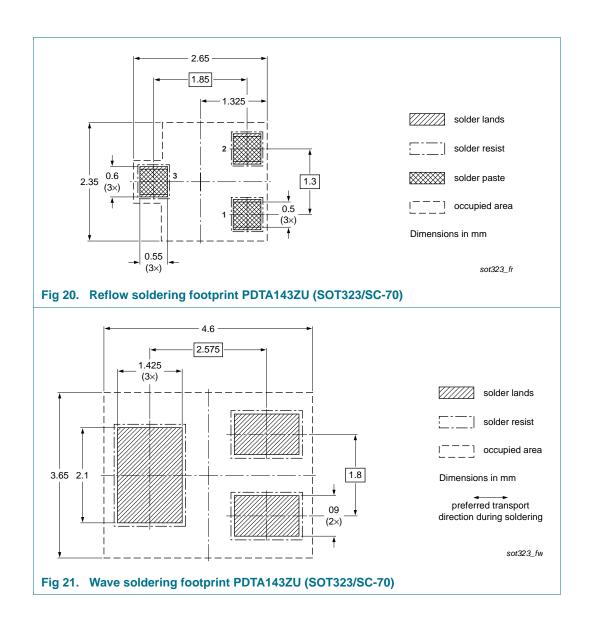
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11. Soldering







12. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
PDTA143Z_SER v.7	20111205	Product data sheet	-	PDTA143Z_SERIES v.6			
Modifications:		f this document has been r NXP Semiconductors.	edesigned to comply wi	ith the new identity			
	 Legal texts h 	ave been adapted to the ne	ew company name whe	re appropriate.			
	 Type number 	rs PDTA143ZEF, PDTA143	ZK and PDTA143ZS re	moved.			
	 Section 1 "Pi 	Section 1 "Product profile": updated					
	 Section 3 "O 	ection 3 "Ordering information": added					
	 Section 4 "M 	ection 4 "Marking": updated					
	• Figure 1 to 11: added						
	 Section 6 "Th 	nermal characteristics": upo	dated				
		<u>racteristics"</u> : V _{i(on)} redefine e input voltage, I _{CEO} update		t voltage, V _{i(off)} redefined to			
	 Section 8 "Te 	est information": added					
	 Section 9 "Page 1 	ackage outline": supersede	d by minimized package	e outline drawings			
	 Section 10 "F 	Packing information": added	b				
	Section 11 "Soldering": added						
	 Section 13 "L 	<u>egal information"</u> : updated					
PDTA143Z_SERIES v.6	20040805	Product data sheet	-	PDTA143Z_SERIES v.5			
PDTA143Z_SERIES v.5	20030908	Product specification	-	PDTA143Z_SERIES v.4			
PDTA143Z_SERIES v.4	20030410	Product specification	-	-			

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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PDTA143Z_SER

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PDTA143Z series

PNP resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

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15. Contents

1	Product profile
1.1	General description
1.2	Features and benefits
1.3	Applications
1.4	Quick reference data 1
2	Pinning information
3	Ordering information
4	Marking 2
5	Limiting values 3
6	Thermal characteristics 4
7	Characteristics 7
8	Test information9
8.1	Quality information
9	Package outline
10	Packing information 10
11	Soldering 11
12	Revision history
13	Legal information
13.1	Data sheet status
13.2	Definitions
13.3	Disclaimers
13.4	Trademarks 16
14	Contact information
15	Contents

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